

Polar™ Power MOSFET HiPerFET™

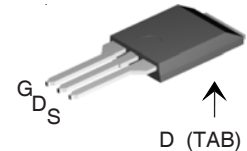
N-Channel Enhancement Mode
Avalanche Rated
Fast Intrinsic Diode

IXFH12N120P
IXFV12N120P
IXFV12N120PS

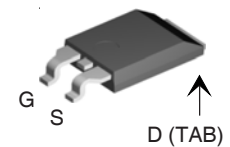


$V_{DSS} = 1200V$
 $I_{D25} = 12A$
 $R_{DS(on)} \leq 1.35\Omega$
 $t_{rr} \leq 300ns$

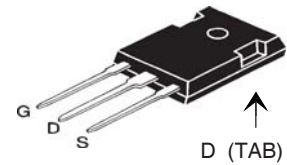
PLUS220 (IXFV)



PLUS220SMD (IXFV_S)



TO-247 (IXFH)



G = Gate D = Drain
S = Source TAB = Drain

| Symbol | Test Conditions | Maximum Ratings | |
|---------------|--|--------------------|------------|
| V_{DSS} | $T_J = 25^\circ C$ to $150^\circ C$ | 1200 | V |
| V_{DGR} | $T_J = 25^\circ C$ to $150^\circ C$, $R_{GS} = 1M\Omega$ | 1200 | V |
| V_{GSS} | Continuous | ± 30 | V |
| V_{GSM} | Transient | ± 40 | V |
| I_{D25} | $T_C = 25^\circ C$ | 12 | A |
| I_{DM} | $T_C = 25^\circ C$, pulse width limited by T_{JM} | 30 | A |
| I_A | $T_C = 25^\circ C$ | 6 | A |
| E_{AS} | $T_C = 25^\circ C$ | 500 | mJ |
| dV/dt | $I_S \leq I_{DM}$, $V_{DD} \leq V_{DSS}$, $T_J \leq 150^\circ C$ | 15 | V/ns |
| P_D | $T_C = 25^\circ C$ | 543 | W |
| T_J | | -55 ... +150 | $^\circ C$ |
| T_{JM} | | 150 | $^\circ C$ |
| T_{stg} | | -55 ... +150 | $^\circ C$ |
| T_L | Maximum lead temperature for soldering | 300 | $^\circ C$ |
| T_{SOLD} | Plastic body for 10s | 260 | $^\circ C$ |
| M_d | Mounting torque (TO-247) | 1.13/10 | Nm/lb.in. |
| F_C | Mounting force (PLUS 220) | 11..65 / 2.5..14.6 | N/lb. |
| Weight | TO-247 | 6 | g |
| | PLUS 220 types | 4 | g |

| Symbol | Test Conditions ($T_J = 25^\circ C$, unless otherwise specified) | Characteristic Values | | |
|--------------|---|-----------------------|------|--------------------|
| | | Min. | Typ. | Max. |
| BV_{DSS} | $V_{GS} = 0V$, $I_D = 1mA$ | 1200 | | V |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_D = 1mA$ | 3.5 | | 6.5 V |
| I_{GSS} | $V_{GS} = \pm 30V$, $V_{DS} = 0V$ | | | ± 100 nA |
| I_{DSS} | $V_{DS} = V_{DSS}$ $V_{GS} = 0V$ $T_J = 125^\circ C$ | | | 25 μA 2 mA |
| $R_{DS(on)}$ | $V_{GS} = 10V$, $I_D = 0.5 \cdot I_{D25}$, Note 1 | 1.15 | 1.35 | Ω |

Features

- International standard packages
- Fast recovery diode
- Unclamped Inductive Switching (UIS) rated
- Low package inductance
- easy to drive and to protect

Advantages

- Easy to mount
- Space savings
- High power density

Applications:

- High Voltage Switched-mode and resonant-mode power supplies
- High Voltage Pulse Power Applications
- High Voltage Discharge circuits in Lasers Pulsers, Spark Igniters, RF Generators
- High Voltage DC-DC converters
- High Voltage DC-AC inverters

| Symbol | Test Conditions ($T_J = 25^\circ\text{C}$ unless otherwise specified) | Characteristic Values | | |
|--------------|--|-----------------------|------|-------------------------|
| | | Min. | Typ. | Max. |
| g_{fs} | $V_{DS} = 20\text{V}, I_D = 0.5 \cdot I_{D25}$, Note 1 | 5 | 9 | S |
| C_{iss} | $V_{GS} = 0\text{V}, V_{DS} = 25\text{V}, f = 1\text{MHz}$ | | 5400 | pF |
| C_{oss} | | | 290 | pF |
| C_{rss} | | | 40 | pF |
| R_{Gi} | Gate input resistance | | 1.5 | Ω |
| $t_{d(on)}$ | Resistive Switching Times $V_{GS} = 10\text{V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$ $R_G = 2\Omega$ (External) | | 34 | ns |
| t_r | | | 25 | ns |
| $t_{d(off)}$ | | | 62 | ns |
| t_f | | | 34 | ns |
| $Q_{g(on)}$ | $V_{GS} = 10\text{V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$ | | 103 | nC |
| Q_{gs} | | | 29 | nC |
| Q_{gd} | | | 41 | nC |
| R_{thJC} | | | | 0.23 $^\circ\text{C/W}$ |
| R_{thCS} | (TO-247, PLUS 220) | 0.21 | | $^\circ\text{C/W}$ |

| Symbol | Test Conditions ($T_J = 25^\circ\text{C}$ unless otherwise specified) | Characteristic Values | | |
|----------|---|-----------------------|------|---------------|
| | | Min. | Typ. | Max. |
| I_s | $V_{GS} = 0\text{V}$ | | | 12 A |
| I_{SM} | Repetitive, pulse width limited by T_{JM} | | | 48 A |
| V_{SD} | $I_F = I_s, V_{GS} = 0\text{V}$, Note 1 | | | 1.5 V |
| t_{rr} | $I_F = 6\text{A}, -di/dt = 100\text{A}/\mu\text{s}$ | | | 300 ns |
| Q_{RM} | | | 0.5 | μC |
| I_{RM} | $V_R = 100\text{V}, V_{GS} = 0\text{V}$ | | 6 | A |

Note 1: Pulse test, $t \leq 300\mu\text{s}$; duty cycle, $d \leq 2\%$.

PLUS220SMD (IXFV_S) Outline

1. GATE
2. DRAIN (COLLECTOR)
3. SOURCE (EMITTER)
4. DRAIN (COLLECTOR)

| SYM | INCHES | | MILLIMETER | |
|-----|---------|------|------------|-------|
| | MIN | MAX | MIN | MAX |
| A | .169 | .185 | 4.30 | 4.70 |
| A1 | .028 | .035 | 0.70 | 0.90 |
| A2 | .098 | .118 | 2.50 | 3.00 |
| A3 | .000 | .010 | 0.00 | 0.25 |
| b | .035 | .047 | 0.90 | 1.20 |
| b1 | .080 | .095 | 2.03 | 2.41 |
| b2 | .054 | .064 | 1.37 | 1.63 |
| c | .028 | .035 | 0.70 | 0.90 |
| D | .551 | .591 | 14.00 | 15.00 |
| D1 | .512 | .539 | 13.00 | 13.70 |
| E | .394 | .433 | 10.00 | 11.00 |
| E1 | .331 | .346 | 8.40 | 8.80 |
| e | .200BSC | | 5.08 BSC | |
| L | .209 | .228 | 5.30 | 5.80 |
| L1 | .118 | .138 | 3.00 | 3.50 |
| L2 | .035 | .051 | 0.90 | 1.30 |
| L3 | .047 | .059 | 1.20 | 1.50 |
| L4 | .039 | .059 | 1.00 | 1.50 |

PLUS220 (IXFV) Outline

1. GATE
2. DRAIN (COLLECTOR)
3. SOURCE (EMITTER)
4. DRAIN (COLLECTOR)

| SYM | INCHES | | MILLIMETER | |
|-----|---------|------|------------|-------|
| | MIN | MAX | MIN | MAX |
| A | .169 | .185 | 4.30 | 4.70 |
| A1 | .028 | .035 | 0.70 | 0.90 |
| A2 | .098 | .118 | 2.50 | 3.00 |
| b | .035 | .047 | 0.90 | 1.20 |
| b1 | .080 | .095 | 2.03 | 2.41 |
| b2 | .054 | .064 | 1.37 | 1.63 |
| c | .028 | .035 | 0.70 | 0.90 |
| D | .551 | .591 | 14.00 | 15.00 |
| D1 | .512 | .539 | 13.00 | 13.70 |
| E | .394 | .433 | 10.00 | 11.00 |
| E1 | .331 | .346 | 8.40 | 8.80 |
| e | .100BSC | | 2.54 BSC | |
| L | .512 | .551 | 13.00 | 14.00 |
| L1 | .118 | .138 | 3.00 | 3.50 |
| L2 | .035 | .051 | 0.90 | 1.30 |
| L3 | .047 | .059 | 1.20 | 1.50 |

TO-247 (IXFH) Outline

| Dim. | Millimeter | | Inches | |
|----------------|------------|-------|--------|-------|
| | Min. | Max. | Min. | Max. |
| A | 4.7 | 5.3 | .185 | .209 |
| A ₁ | 2.2 | 2.54 | .087 | .102 |
| A ₂ | 2.2 | 2.6 | .059 | .098 |
| b | 1.0 | 1.4 | .040 | .055 |
| b ₁ | 1.65 | 2.13 | .065 | .084 |
| b ₂ | 2.87 | 3.12 | .113 | .123 |
| C | .4 | .8 | .016 | .031 |
| D | 20.80 | 21.46 | .819 | .845 |
| E | 15.75 | 16.26 | .610 | .640 |
| e | 5.20 | 5.72 | 0.205 | 0.225 |
| L | 19.81 | 20.32 | .780 | .800 |
| L1 | | 4.50 | | .177 |
| ∅P | 3.55 | 3.65 | .140 | .144 |
| Q | 5.89 | 6.40 | 0.232 | 0.252 |
| R | 4.32 | 5.49 | .170 | .216 |
| S | 6.15 | BSC | 242 | BSC |

IXYS reserves the right to change limits, test conditions, and dimensions.

| | | | | | | | | | | |
|--|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|--------------|--------------|
| IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: | 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665 | 6,404,065 B1 | 6,683,344 | 6,727,585 | 7,005,734 B2 | 7,157,338 B2 |
| | 4,850,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343 | 6,710,405 B2 | 6,759,692 | 7,063,975 B2 | |
| | 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505 | 6,710,463 | 6,771,478 B2 | 7,071,537 | |

Fig. 1. Output Characteristics @ 25°C

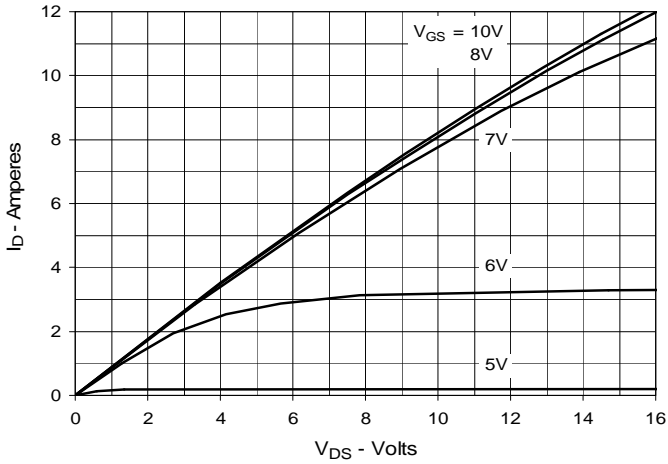


Fig. 2. Extended Output Characteristics @ 25°C

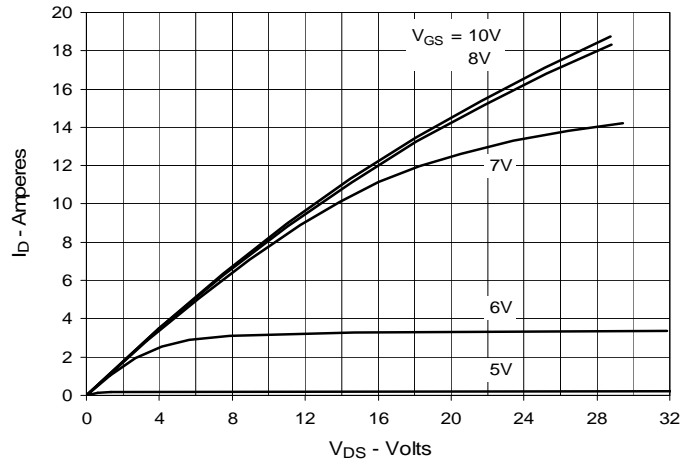


Fig. 3. Output Characteristics @ 125°C

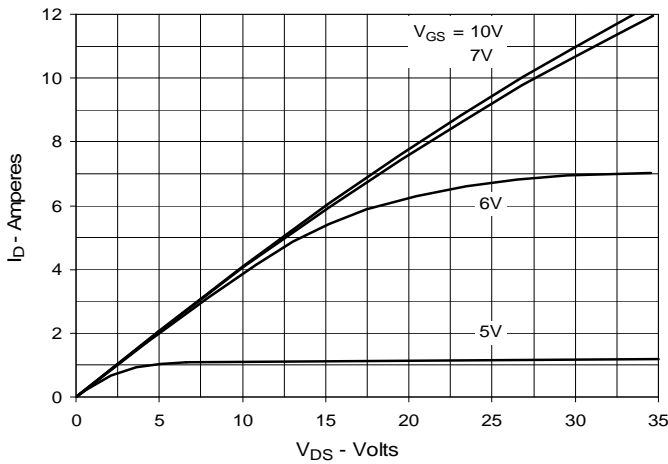


Fig. 4. $R_{DS(on)}$ Normalized to $I_D = 6A$ Value vs. Junction Temperature

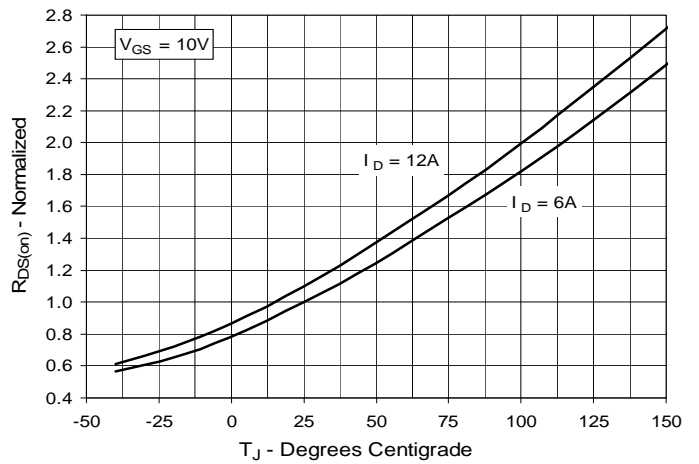


Fig. 5. $R_{DS(on)}$ Normalized to $I_D = 6A$ Value vs. Drain Current

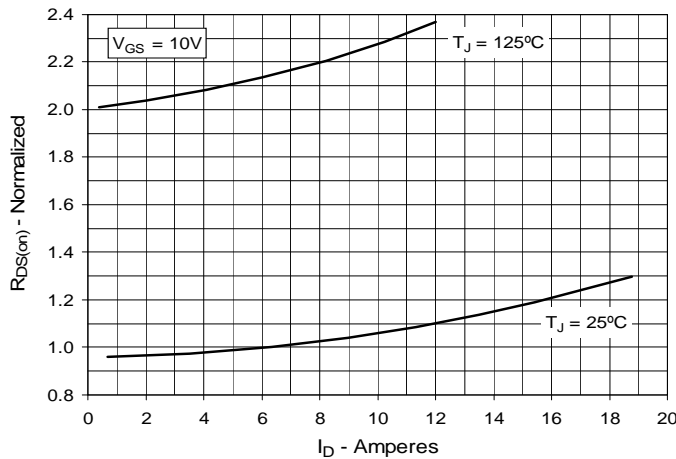


Fig. 6. Maximum Drain Current vs. Case Temperature

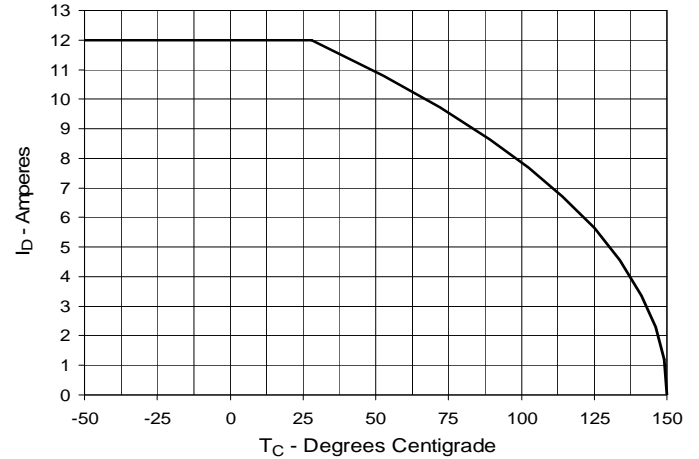


Fig. 7. Input Admittance

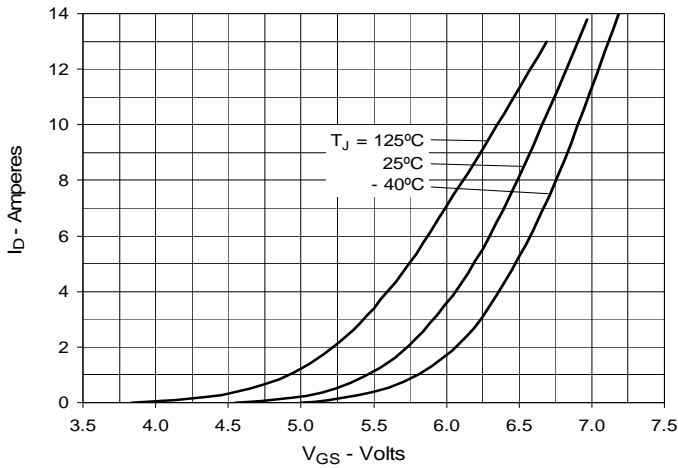


Fig. 8. Transconductance

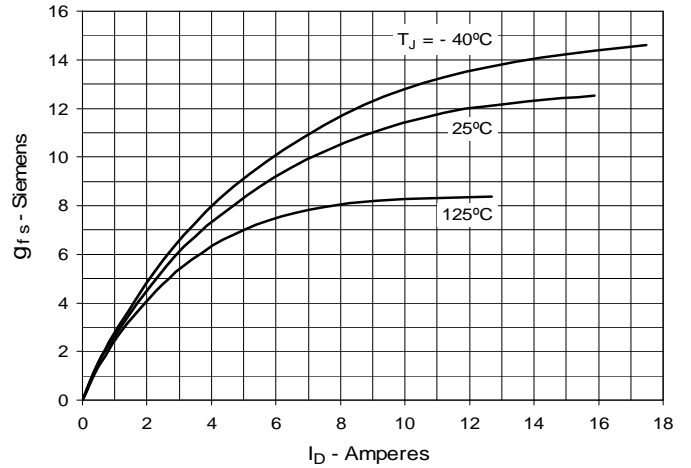


Fig. 9. Forward Voltage Drop of Intrinsic Diode

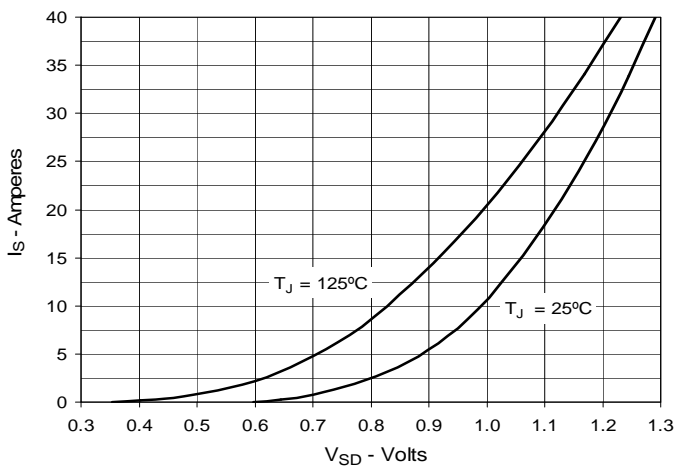


Fig. 10. Gate Charge

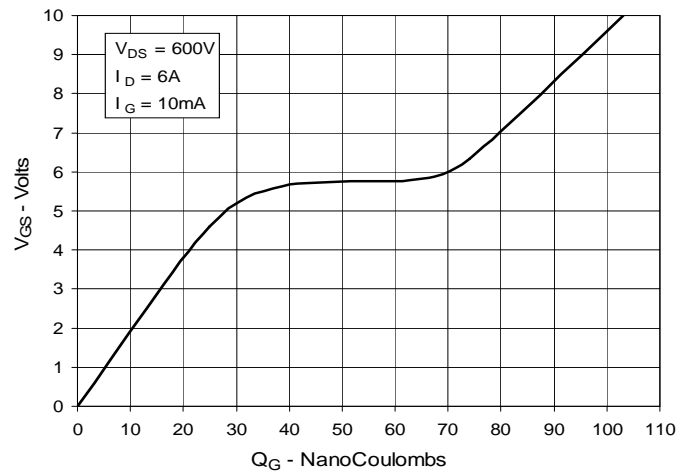


Fig. 11. Capacitance

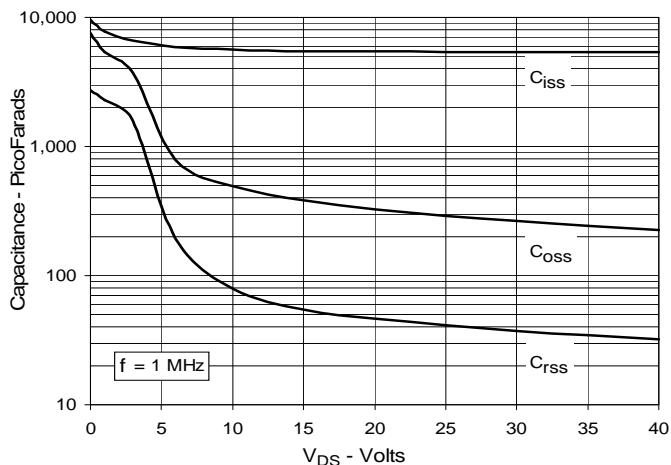
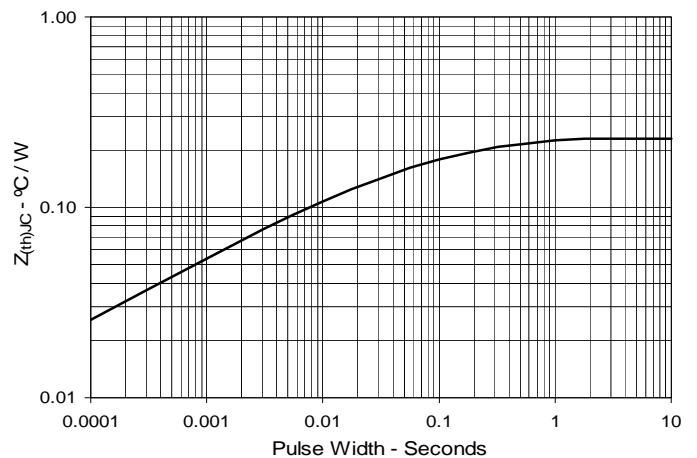


Fig. 12. Maximum Transient Thermal Impedance





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